NSN 5962-01-157-9902

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View Online at https://aerobasegroup.com/nsn/5962-01-157-9902 **Body Length:** 0.440 inches **Body Width:** Between 0.248 inches and 0.325 inches **Body Height:** 0.085 inches **Maximum Power Dissipation Rating:** 910.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and programmed and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 16 flat leads Shelf Life: N/a

Demilitarization:

Unit Of Measure:

Yes - demil/mli

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